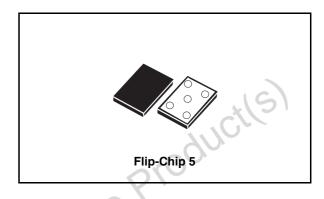


## ST1G3234

## 1-bit dual supply bus buffer level translator with A-side series resistor

#### **Features**

- High speed: t<sub>PD</sub> = 4.4ns (Max.) at T<sub>A</sub> = 85°C V<sub>CCB</sub> = 1.65V; V<sub>CCA</sub> = 3.0V
- Low power dissipation:
  I<sub>CCA</sub> = I<sub>CCB</sub> = 5μA(Max.) at T<sub>A</sub> = 85°C
- Symmetrical output impedance: II<sub>OHA</sub>| = I<sub>OLA</sub> = 10mA Min at V<sub>CCA</sub> = 2.75V; V<sub>CCB</sub> = 1.4V to 3.6V II<sub>OHA</sub>| = I<sub>OLA</sub> = 6mA Min at V<sub>CCA</sub> = 2.3V; V<sub>CCB</sub> = 1.4V to 3.6V
- Balanced propagation delays: t<sub>PLH</sub> ≅ t<sub>PHL</sub>
- Power down protection on inputs and outputs
- $26\Omega$  series resistor on A-side outputs
  - Operating voltage range:
     V<sub>CCA</sub>(Opr) = 1.4V to 3.6V (1.2V data retent)
     V<sub>CCB</sub>(Opr) = 1.4V to 3.6V (1.2V data retent)
- Max data rates:
   380Mbps (1.8V to 3.3V translation)
   260Mbps (<1.8V to 3.3V translation)</li>
   260Mbps (translate to 2.5V)
   210Mbps (translate to 1.5V)
- Latch-up performance exceeds 500mA (JESD 17)
- ESD performance: HBM > 2000V (MIL STD 883 method 3015); MM > 200V
- R<sub>O</sub>HS compliant for Flip-Chip package



### Description

The ST1G3234 is a dual supply low voltage CMOS 1-Bit bus buffer level translator fabricated with sub-micron silicon gate and five-layer metal wiring C<sup>2</sup>MOS technology. Designed for use as an interface between a 3.3V bus and a 2.5V or 1.8V bus in a mixed 3.3V/1.8V, 3.3V/2.5V, 1.8V/1.4V and 2.5V/1.8V supply systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

This IC is intended for one-way asynchronous communication between data buses. The input and output power down protections disable the device when both power supply are down, so that the buses are effectively isolated.

The input tolerant buffers allow to translate  $V_{CCB}$  compatible signals and greater signals than  $V_{CCB}$  up/down to  $V_{CCA}$ .

All inputs are equipped with protection circuits against static discharge, giving them ESD immunity and transient excess voltage.

#### Order codes

Part number	Package	Comments
ST1G3234BJR	Flip-Chip 5	4000 parts per reel

Contents ST1G3234

## **Contents**

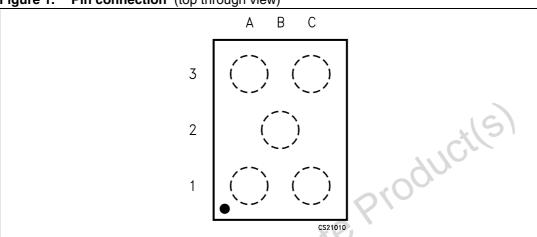
1	Pin settings 3
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	1.2 Pin description
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ST1G3234 Pin settings

## 1 Pin settings

## 1.1 Pin connection

Figure 1. Pin connection (top through view)



## 1.2 Pin description

Table 1. Pin description

Pin N°	Symbol	Name and function
A1	A1	Data output (V <sub>CCA</sub> referred)
C1	B1	Data input (V <sub>CCB</sub> referred)
B2	GND	Ground (0V)
АЗ	V <sub>CCA</sub>	Positive supply voltage
СЗ	V <sub>CCB</sub>	Positive supply voltage
Obsole		

Device summary ST1G3234

## 2 Device summary

Figure 2. Input equivalent circuit

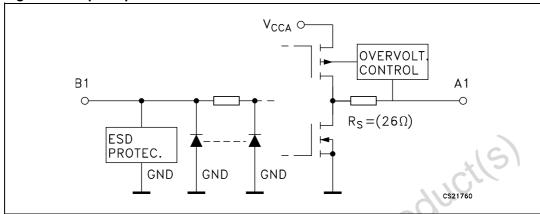


Figure 3. Logic diagram

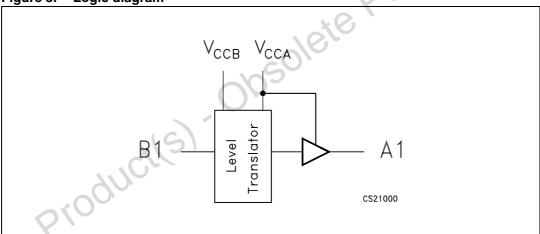


Table 2. Truth table

Inputs B1 (V <sub>CCB</sub> Referred)	Outputs A1 (V <sub>CCA</sub> Referred)			
L	L			
Н	Н			

ST1G3234 Maximum rating

## 3 Maximum rating

Stressing the device above the rating listed in the "Absolute Maximum Ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

Table 3. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V <sub>CCA</sub>	Output supply voltage	-0.5 to +4.6	V
V <sub>CCB</sub>	Input supply voltage	-0.5 to + 4.6	٧
V <sub>OA</sub>	DC output voltage (power down mode: V <sub>CCA</sub> =V <sub>CCB</sub> =Gnd)	-0.5 to +4.6	V
V <sub>IB</sub>	DC input voltage (power down mode: V <sub>CCA</sub> =V <sub>CCB</sub> =Gnd)	-0.5 to +4.6	V
V <sub>OA</sub>	DC output voltage	-0.5 to V <sub>CCA</sub> + 0.5	V
V <sub>IB</sub>	DC input voltage	-0.5 to + 4.6	V
I <sub>IK</sub>	DC input diode current	-20	mA
lok	DC output diode current	-50	mA
I <sub>OA</sub>	DC output current	±50	mA
I <sub>CCA</sub>	DC V <sub>CCA</sub> or ground current	±100	mA
I <sub>CCB</sub>	DC V <sub>CCB</sub> or ground current	±100	mA
P <sub>d</sub>	Power dissipation	200	mW
T <sub>stg</sub>	Storage temperature	-65 to +150	°C
TL	Lead temperature (10 sec)	260	°C

ST1G3234 **Maximum rating** 

#### **Recommended operating conditions** 3.1

Table 4. Recommended operating conditions

V	Paramet	er	Value	Unit
$V_{CCA}$	Supply voltage		1.4 to 3.6	٧
V <sub>CCB</sub>	Supply voltage		1.4 to 3.6	V
$V_{IB}$	Input voltage (B1)		0 to V <sub>CCB</sub>	٧
V <sub>OA</sub>	Output voltage (A1)		0 to V <sub>CCA</sub>	٧
T <sub>op</sub>	Operating temperature		-40 to 85	°C
_		V <sub>CCB</sub> = 3.0 to 3.6V	0 to 10	ns/V
dt/dv	Input Rise and Fall Time (1)	$V_{CCB} = 2.3 \text{ to } 2.7 \text{V}$	0 to 20	ns/V
		$V_{CCB} = 1.4 \text{ to } 1.95 \text{V}$	0 to 100	ns/V
	0.8V to 2.0V at V <sub>CC</sub> = 3.0V	)050,		

## 4 Electrical characteristics

Table 5. DC specification

		Test condition			Value						
Symbol	Parameter	V <sub>CCB</sub>	V <sub>CCA</sub>		<b>T</b> <sub>A</sub> = 3	25 °C	-40 to	85 °C	Unit		
		(V) <sup>(1)</sup>	(V) <sup>(1)</sup>		Min	Max	Min	Max			
		1.4			0.65V <sub>CCB</sub>		0.65V <sub>CCB</sub>				
V <sub>IHB</sub>	High level input	1.8	1.4 to		0.65V <sub>CCB</sub>		0.65V <sub>CCB</sub>		٧		
* IHB	voltage	2.5	3.6V		1.6		1.6	.15	Ň		
		3.3			2.0		2.0	CILL	,		
		1.4				0.35V <sub>CCB</sub>		0.35V <sub>CCB</sub>			
V <sub>ILB</sub>	Low level input	1.8	1.4 to			0.35V <sub>CCB</sub>	(00	0.35V <sub>CCB</sub>	٧		
ILB	voltage	2.5	3.6V			0.7		0.7			
		3.3				0.8		0.8			
			1.4	I <sub>O</sub> =-100μA	1.2	,	1.2				
			2.75	I <sub>O</sub> =-10mA	2.2		2.2		V		
V <sub>OHA</sub>	High level output voltage	1.4 to 3.6V	2.3	I <sub>O</sub> =-6mA	1.8		1.8		V		
					1.65	I <sub>O</sub> =-2mA	1.4		1.4		
			1.4	I <sub>O</sub> =-1mA	1.1		1.1				
		21	1.4	I <sub>O</sub> =100μA		0.20		0.20			
		$O_{O}$	2.75	I <sub>O</sub> =1mA		0.40		0.40			
\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	Low level output	1.4 to	2.75	I <sub>O</sub> =10mA		0.55		0.55	V		
V <sub>OLA</sub>	voltage	3.6V	2.3	I <sub>O</sub> =6mA		0.40		0.40	V		
	10.		1.65	I <sub>O</sub> =2mA		0.25		0.25			
5			1.4	I <sub>O</sub> =1mA		0.20		0.20			
	Input leakage	2.7	3.6	V <sub>IB</sub> =V <sub>CCB</sub> or GND		±0.5		±5	μА		
I <sub>IB</sub>	current	1.4	2.7	V <sub>IB</sub> =3.6V or GND		±0.5		±5	μА		
I <sub>OFF</sub>	Power OFF leakage current	0	0	V <sub>IB</sub> =GND to 3.6V V <sub>OA</sub> =GND to 3.6V		±1.0		±10	μА		
I <sub>CCtB</sub>	Quiescent supply current	1.4 to 3.6V	1.4 to 3.6V	V <sub>IB</sub> =V <sub>CCB</sub> or GND		0.5		5	μА		
I <sub>CCtA</sub>	Quiescent supply current	1.4 to 3.6V	1.4 to 3.6V	V <sub>IB</sub> =V <sub>CCB</sub> or GND		0.5		5	μΑ		

<sup>1.</sup>  $V_{CC}$  range = 3.3 ± 0.3; 2.5 ± 0.2V; 1.8 ± 0.15V

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Electrical characteristics ST1G3234

Table 6. AC electrical characteristics

			Test conditio	n	Va		
Symbol	Parameter	V <sub>CCB</sub>	V <sub>CCA</sub>		-40 to	85 °C	Unit
		(V)	(V)		Min	Max	
		2.3 to 3.6	1.4		2.0	5.0	
		1.4 to 1.95	1.4		2.0	5.0	
		2.3 to 3.6	1.65 to 1.95		2.0	4.5	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay time B1 to A1	1.4 to 1.95	1.65 to 1.95	C <sub>L</sub> = 10 pF	2.0	4.8	ns
		1.4 to 1.95	2.3 to 2.7		2.0	3.5	
		1.4 to 1.95	3.0 to 3.6		2.0	3.5	1
		2.3 to 2.7	3.0 to 3.6		1.0	3.0	
		2.3 to 3.6	1.4		2.0	5.5	
		1.4 to 1.95	1.4	010	2.0	5.5	
		2.3 to 3.6	1.65 to 1.95	00.75	2.0	5.0	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay time B1 to A1	1.4 to 1.95	1.65 to 1.95	$C_L = 30 \text{ pF}$ $R_L = 500 \Omega$	2.0	5.2	ns
		1.4 to 1.95	2.3 to 2.7	_	2.0	4.0	
		1.4 to 1.95	3.0 to 3.6		2.0	4.0	
		2.3 to 2.7	3.0 to 3.6		1.0	3.5	

**Table 7. Capacitance characteristics** 

				Test condition			Value				
Symbol	Parameter	V <sub>CCB</sub>	V <sub>CCA</sub>		T,	<sub>A</sub> = 25 °	,C	-40 to	85 °C	Unit	
	010	(V)	(V)		Min	Тур	Max	Min	Max		
C <sub>INB</sub>	Input capacitance	open	open			5				pF	
Co	Output capacitance	2.5	3.3			6				pF	
60		2.5	3.3			27					
0,		1.8	3.3			27					
C <sub>PD</sub>	Power dissipation capacitance	1.4	2.5	f = 10MHz		23				pF	
		1.4	1.8			20					
		3.3	1.8			27					

Note: 1  $C_{PD}$  is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average current can be obtained by the following equation.  $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4$  (per circuit)

ST1G3234 Test circuit

## 5 Test circuit

Figure 4. Test circuit

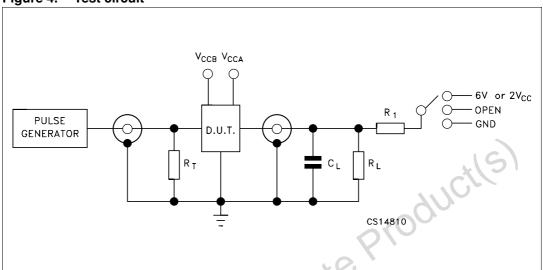


Table 8. Test circuit

Test	Switch
t <sub>PLH</sub> , t <sub>PHL</sub>	Open

 $C_L = 10/30 pF$  or equivalent (includes jig and probe capacitance)

 $R_L = R_1 = 500\Omega$  or equivalent

 $R_T = Z_{OUT}$  of pulse generator (typically  $50\Omega$ )

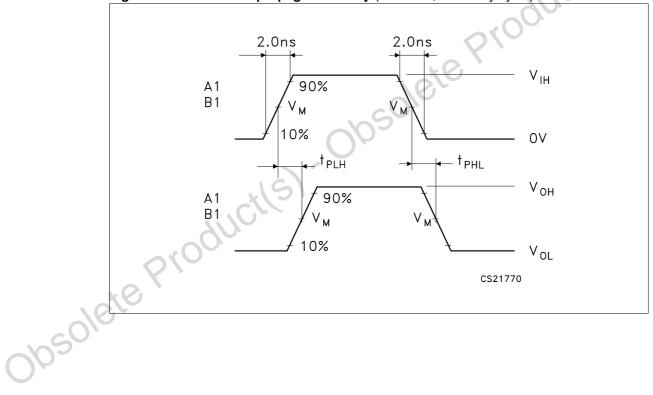
Waveforms ST1G3234

## 6 Waveforms

Table 9. Waveform symbol value

Symbol	V <sub>CC</sub>					
Symbol	3.0 to 3.6V	2.3 to 2.7V	1.65 to 1.95V			
V <sub>IH</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>			
V <sub>M</sub>	1.5V	V <sub>CC</sub> /2	V <sub>CC</sub> /2			
V <sub>X</sub>	V <sub>OL</sub> +0.3V	V <sub>OL</sub> +0.15V	V <sub>OL</sub> +0.15V			
V <sub>Y</sub>	V <sub>OL</sub> -0.3V	V <sub>OL</sub> -0.15V	V <sub>OL</sub> -0.15V			

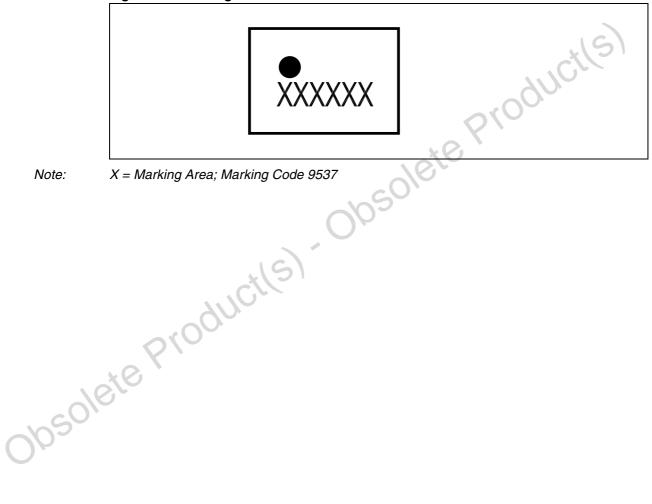
Figure 5. Waveform - propagation delay (f = 1MHz; 50% duty cycle)



#### Package mechanical data 7

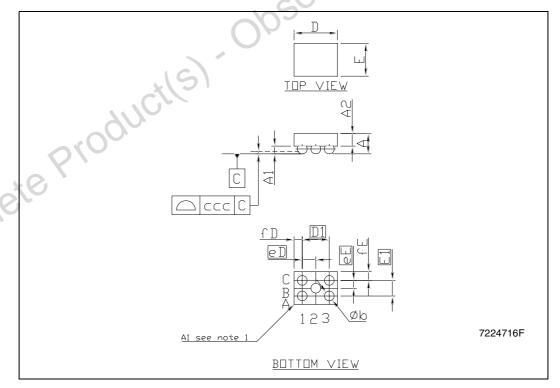
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Figure 6. Marking



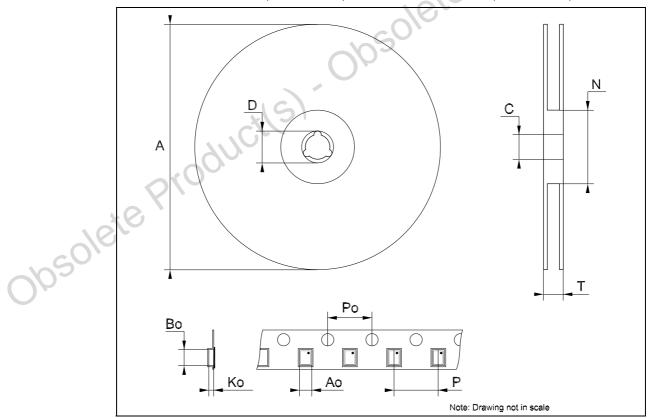
#### Flip-Chip 5 MECHANICAL DATA

DIM		mm.		mils			
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.	
Α	0.585	0.65	0.715	23.0	25.6	28.1	
A1	0.21	0.25	0.29	8.3	9.8	11.4	
a2		0.40			15.7		
b	0.265	0.315	0.365	10.4	12.4	14.4	
D	1.31	1.36	1.41	51.6	53.5	55.5	
D1		0.866			34.1	16	
Е	0.97	1.02	1.07	38.2	40.2	42.1	
E1		0.5			19.7	)	
eD	0.383	0.433	0.483	15.1	17.0	19.0	
еE	0.20	0.25	0.30	7.9	9.8	11.8	
fD		0.247			9.7		
fE		0.260		260	10.2		
ccc		0.080		0	3.1		



Tape & Reel Flip-Chip	ว 5 I	MECHANICAL	. DATA
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DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
Α			178			6.926
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	49	50	51	1.929	1.969	2.008
Т			12.4			0.488
Ao	1.60	1.65	1.70	0.063	0.065	0.067
Во	1.27	1.32	1.37	0.050	0.052	0.054
Ko	0.76	0.81	0.86	0.030	0.032	0.034
Po	3.9	4	4.1	0.153	0.157	0.161
Р	3.9	4	4.1	0.153	0.157	0.161



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Revision history ST1G3234

## 8 Revision history

Table 10. Revision history

	Date	Revision	Changes			
	14-Oct-2004	1	First release.			
	20-Dec-2004	2	Revision on <i>Table 3</i> .			
	11-Feb-2005	3	Add Tape & Reel, Figures 2, 3, 5, 6, <i>Table 3, 5, 7</i> and Mechanical Data has been modified.			
	30-Mar-2005	4	Add features ==> Max data rates.			
	09-May-2005	5	Table 7 and Table 8 have been updated.			
	16-Aug-2006	6	New template, updated test condition V <sub>OHA</sub> <i>Table 5</i>			
Obsolete Product(s). Obsolete Produc						

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